### **AUTOMOTIVE GRADE**

PD-96302A

# International TOR Rectifier

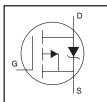
# AUIRFR6215 HEXFET® Power MOSFET

#### **Features**

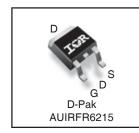
- P-Channel
- Low On-Resistance
- Dynamic dV/dT Rating
- 175°C Operating Temperature
- Fast Switching
- Fully Avalanche Rated
- Repetitive Avalanche Allowed up to Tjmax
- Lead-Free, RoHS Compliant
- Automotive Qualified \*

### **Description**

Specifically designed for Automotive applications of HEXFET® Power MOSFETs utilizes the latest processing techniques to achieve low on-resistance per silicon area. This benefit combined with the fast switching speed and ruggedized device design that HEXFET power MOSFETs are well known for, provides the designer with an extremely efficient and reliable device for use in Automotive and a wide variety of other applications.



V <sub>(BR)DSS</sub>		-150V
R <sub>DS(on)</sub>	max.	$0.295\Omega$
I <sub>D</sub>		-13A



G	D	S
Gate	Drain	Source

#### **Absolute Maximum Ratings**

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only; and functional operation of the device at these or any other condition beyond those indicated in the specifications is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions. Ambient temperature (T<sub>A</sub>) is 25°C, unless otherwise specified.

	Parameter	Max.	Units
I <sub>D</sub> @ T <sub>C</sub> = 25°C	Continuous Drain Current, V <sub>GS</sub> @ 10V	-13	
$I_D @ T_C = 100^{\circ}C$	Continuous Drain Current, V <sub>GS</sub> @ 10V	-9.0	Α
I <sub>DM</sub>	Pulsed Drain Current ①⑤	-44	
$P_D @ T_C = 25^{\circ}C$	Maximum Power Dissipation	110	W
	Linear Derating Factor	0.71	W/°C
$V_{GS}$	Gate-to-Source Voltage	± 20	V
E <sub>AS</sub>	Single Pulse Avalanche Energy (Thermally limited) © 6	310	mJ
I <sub>AR</sub>	Avalanche Current ①⑤	-6.6	Α
E <sub>AR</sub>	Repetitive Avalanche Energy ① ⑥	11	mJ
dv/dt	Peak Diode Recovery ③	5.0	V/ns
$T_J$	Operating Junction and	-55 to + 175	
T <sub>STG</sub>	Storage Temperature Range		°C
	Soldering Temperature, for 10 seconds (1.6mm from case)	300	

#### **Thermal Resistance**

	Parameter		Max.	Units
$R_{\theta JC}$	Junction-to-Case ®®		1.4	
$R_{\theta JA}$	Junction-to-Ambient(PCB mount)⑦		50	°C/W
$R_{\theta JA}$	Junction-to-Ambient		110	

HEXFET® is a registered trademark of International Rectifier.

<sup>\*</sup>Qualification standards can be found at http://www.irf.com/

## Static Electrical Characteristics @ $T_J = 25$ °C (unless otherwise specified)

	Parameter	Min.	Тур.	Max.	Units	Conditions
$V_{(BR)DSS}$	Drain-to-Source Breakdown Voltage	-150			٧	$V_{GS} = 0V, I_D = -250\mu A$
$\Delta V_{(BR)DSS}/\Delta T_J$	Breakdown Voltage Temp. Coefficient		-0.20		V/°C	Reference to 25°C, I <sub>D</sub> = -1mA <sup>①</sup>
R <sub>DS(on)</sub>	Static Drain-to-Source On-Resistance			0.295		V <sub>GS</sub> = -10V, I <sub>D</sub> = -6.6A ⊕
nDS(on)	Static Dialit-to-Source Off-Resistance			0.58	Ω	$V_{GS} = -10V, I_D = -6.6A \oplus T_J = 150^{\circ}C$
$V_{GS(th)}$	Gate Threshold Voltage	-2.0		-4.0	V	$V_{DS} = V_{GS}$ , $I_D = -250\mu A$
gfs	Forward Transconductance	3.6			S	$V_{DS} = -50V, I_{D} = -6.6A$ ©
I <sub>DSS</sub>	Drain-to-Source Leakage Current			-25	μA	$V_{DS} = -150V, V_{GS} = 0V$
				-250	μΑ	$V_{DS} = -120V, V_{GS} = 0V, T_{J} = 150^{\circ}C$
I <sub>GSS</sub>	Gate-to-Source Forward Leakage			100	nA	V <sub>GS</sub> = 20V
	Gate-to-Source Reverse Leakage			-100	I IIA	V <sub>GS</sub> = -20V

## Dynamic Electrical Characteristics @ $T_J = 25^{\circ}C$ (unless otherwise specified)

	Parameter	Min.	Тур.	Max.	Units	Conditions	
Q <sub>g</sub>	Total Gate Charge			66		I <sub>D</sub> = -6.6A	
Q <sub>gs</sub>	Gate-to-Source Charge			8.1	nC	V <sub>DS</sub> =-120V	
$Q_{gd}$	Gate-to-Drain ("Miller") Charge			35		V <sub>GS</sub> = -10V, See Fig 6 and 13 ⊕ ®	
t <sub>d(on)</sub>	Turn-On Delay Time		14			$V_{DD} = -75V$	
t <sub>r</sub>	Rise Time		36			$I_D = -6.6A$	
t <sub>d(off)</sub>	Turn-Off Delay Time		53		ns	$R_G = 6.8\Omega$	
t <sub>f</sub>	Fall Time		37			$R_D = 12\Omega$ , See Fig. 10 $\oplus$ $\odot$	
L <sub>D</sub>	Internal Drain Inductance		4.5			Between lead, 6mm (0.25in.)	
L <sub>S</sub>	Internal Source Inductance		7.5			from package and center of die contact	
C <sub>iss</sub>	Input Capacitance		860			$V_{GS} = 0V$	
Coss	Output Capacitance		220		pF	$V_{DS} = -25V$	
C <sub>rss</sub>	Reverse Transfer Capacitance		130			f = 1.0MHz, See Fig.5 ®	

### **Diode Characteristics**

	Parameter	Min.	Тур.	Max.	Units	Conditions
Is	Continuous Source Current			-13		MOSFET symbol
	(Body Diode)				Α	showing the
I <sub>SM</sub>	Pulsed Source Current			-44	_ ^	integral reverse
	(Body Diode) ① ®			-44		p-n junction diode.
$V_{SD}$	Diode Forward Voltage			-1.6	V	$T_J = 25^{\circ}C, I_S = -6.6A, V_{GS} = 0V \oplus$
t <sub>rr</sub>	Reverse Recovery Time		160	240	ns	$T_J = 25^{\circ}C, I_F = -6.6A$
Q <sub>rr</sub>	Reverse Recovery Charge	_	1.2	1.7	μC	di/dt = 100A/µs ⊕®
t <sub>on</sub>	Forward Turn-On Time	Intrinsi	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)			

Notes ① through ® are on page 10

## Qualification Information<sup>†</sup>

		Automotive (per AEC-Q101) ††			
		Comments: This part number(s) passed Automotive qualification. IR's Industrial and Consume qualification level is granted by extension of the higher Automotive level.			
Moisture Sensitivity Level		D PAK MSL1			
	Machine Model		Class M4		
		AEC-Q101-002			
	Human Body Model	Class H3A			
ESD		AEC-Q101-001			
	Charged Device Model	Class C5			
		AEC-Q101-005			
RoHS Compliant	npliant Yes		Yes		

<sup>†</sup> Qualification standards can be found at International Rectifier's web site: http://www.irf.com/

<sup>††</sup> Exceptions to AEC-Q101 requirements are noted in the qualification report.

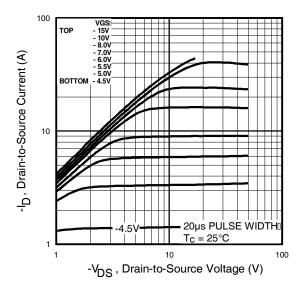


Fig 1. Typical Output Characteristics

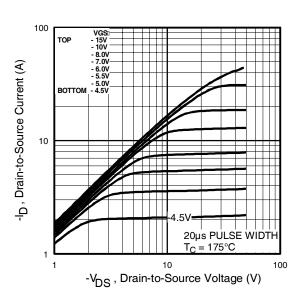


Fig 2. Typical Output Characteristics

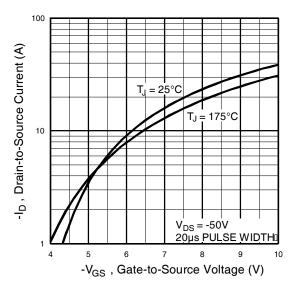
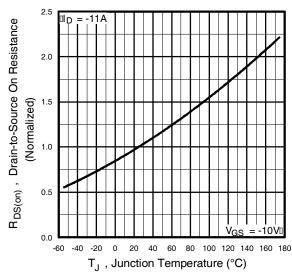
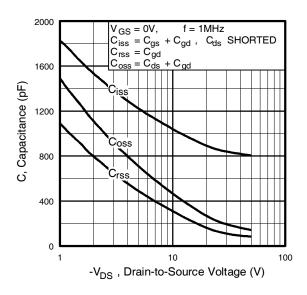


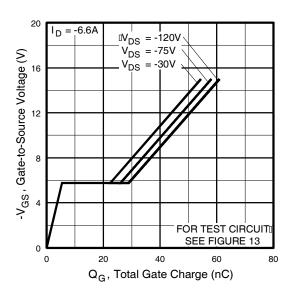
Fig 3. Typical Transfer Characteristics



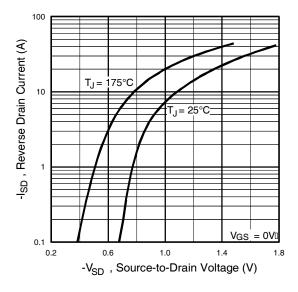
**Fig 4.** Normalized On-Resistance Vs. Temperature



**Fig 5.** Typical Capacitance Vs. Drain-to-Source Voltage



**Fig 6.** Typical Gate Charge Vs. Gate-to-Source Voltage



**Fig 7.** Typical Source-Drain Diode Forward Voltage

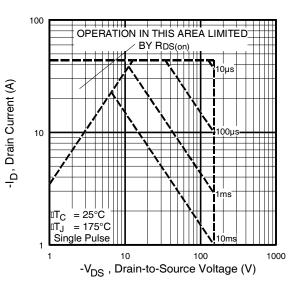
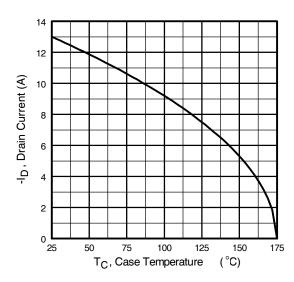


Fig 8. Maximum Safe Operating Area



**Fig 9.** Maximum Drain Current Vs. Case Temperature

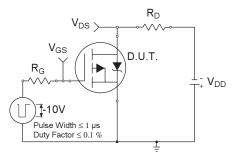


Fig 10a. Switching Time Test Circuit

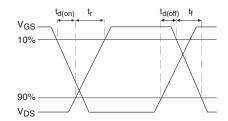


Fig 10b. Switching Time Waveforms

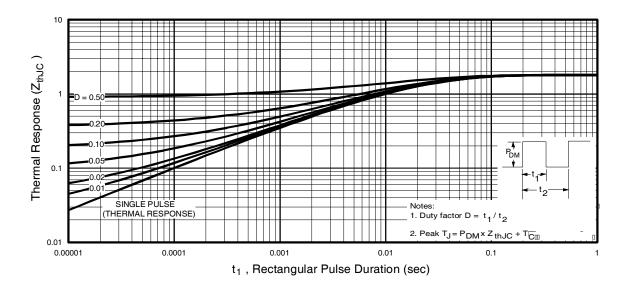


Fig 11. Maximum Effective Transient Thermal Impedance, Junction-to-Case

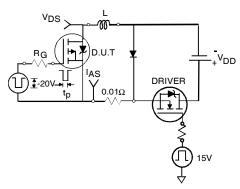


Fig 12a. Unclamped Inductive Test Circuit

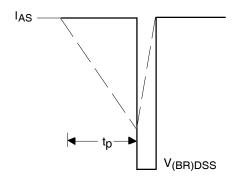


Fig 12b. Unclamped Inductive Waveforms

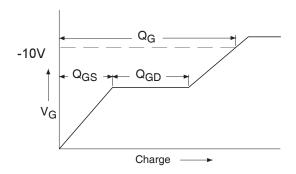
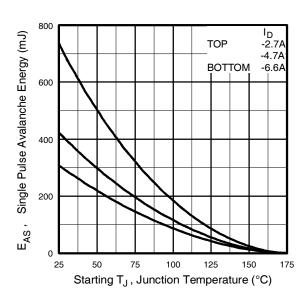


Fig 13a. Basic Gate Charge Waveform



**Fig 12c.** Maximum Avalanche Energy Vs. Drain Current

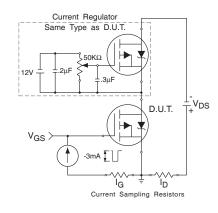
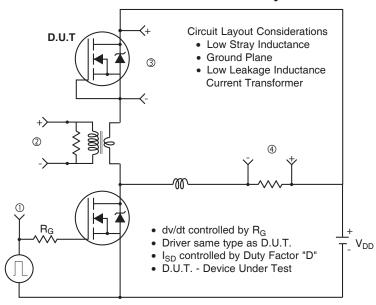


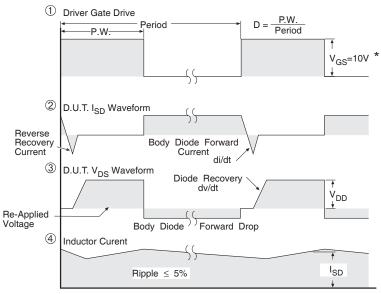
Fig 13b. Gate Charge Test Circuit

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### Peak Diode Recovery dv/dt Test Circuit



\* Reverse Polarity of D.U.T for P-Channel

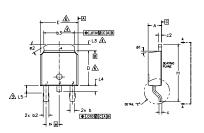


\* V<sub>GS</sub> = 5V for Logic Level Devices

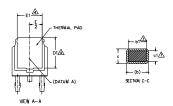
Fig 14. For N-Channel HEXFETS

## D-Pak (TO-252AA) Package Outline

Dimensions are shown in millimeters (inches)







- 1.- DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994
- 2.- DIMENSION ARE SHOWN IN INCHES [MILLIMETERS].
- A- LEAD DIMENSION UNCONTROLLED IN L5.
- △ DIMENSION D1, E1, L3 & b3 ESTABLISH A MINIMUM MOUNTING SURFACE FOR THERMAL PAD.
- 5.- SECTION C-C DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN .005 AND 0.10 [0.13 AND 0.25] FROM THE LEAD TIP.
- DIMENSION D & E DO NOT INCLUDE MOLD FLASH, MOLD FLASH SHALL NOT EXCEED .005 [0.13] PER SIDE, THESE DIMENSIONS ARE MEASURED AT THE OUTMOST EXTREMES OF THE PLASTIC BODY,

  DIMENSION bi & cl APPLIED TO BASE METAL ONLY.
- DATUM A & B TO BE DETERMINED AT DATUM PLANE H.

  9. OUTLINE CONFORMS TO JEDEC OUTLINE TO -252AA.

					_
S Y M		Ŋ			
B	MILLIM	ETERS	INC	O T E S	
0	MIN.	MAX.	MIN.	MAX.	E S
Α	2.18	2.39	.086	.094	
A1	-	0.13	-	.005	
b	0.64	0.89	.025	.035	
ь1	0.65	0.79	.025	.031	7
b2	0.76	1,14	.030	.045	
b3	4.95	5,46	.195	.215	4
С	0.46	0.61	.018	.024	
c1	0,41	0,56	.016	.022	7
c2	0,46	0.89	.018	.035	
D	5.97	6.22	.235	.245	6
D1	5,21	-	.205	-	4
E	6.35	6.73	.250	.265	6
E1	4.32	-	.170	-	4
e	2.29	BSC	.090	BSC	
н	9.40	10.41	.370	.410	
L	1.40	1.78	.055	.070	
L1	2,74	BSC	.108	REF.	
L2	0,51	BSC	.020 BSC		
L3	0.89	1.27	.035	.050	4
L4	-	1.02	-	.040	
L5	1,14	1.52	.045	.060	3
ø	0.	10*	0,	10*	
Ø1	0.	15*	0,	15*	
ø2	25*	35*	25	35	

#### LEAD ASSIGNMENTS

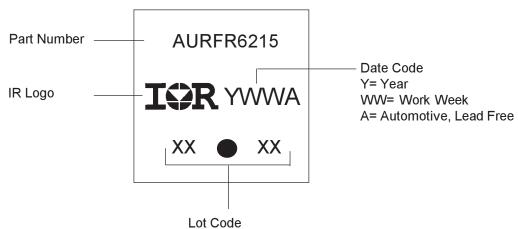
#### **HEXFET**

- 1.- GATE 2.- DRAIN 3.- SOURCE 4.- DRAIN

#### IGBT & CoPAK

- 1.- GATE 2.- COLLECTOR 3.- EMITTER 4.- COLLECTOR

## D-Pak Part Marking Information

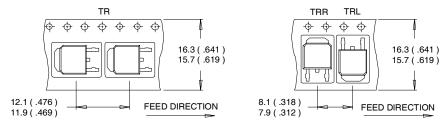


Note: For the most current drawing please refer to IR website at http://www.irf.com/package/ www.irf.com

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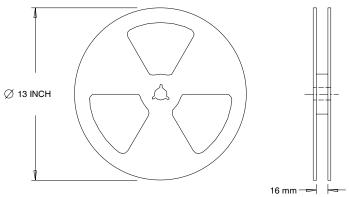
## D-Pak (TO-252AA) Tape & Reel Information

Dimensions are shown in millimeters (inches)



#### NOTES:

- 1. CONTROLLING DIMENSION: MILLIMETER.
- 2. ALL DIMENSIONS ARE SHOWN IN MILLIMETERS (INCHES).
  3. OUTLINE CONFORMS TO EIA-481 & EIA-541.



1. OUTLINE CONFORMS TO EIA-481.

#### Notes:

- $\ensuremath{\mathbb{T}}$  Repetitive rating; pulse width limited by
- max. junction temperature. (See fig. 11)

  ② Starting  $T_J = 25^{\circ}C$ ,  $L = 14mH R_G = 25\Omega$ ,  $I_{AS} = -6.6A$ . (See Fig.12)

  ③  $I_{SD} \le -6.6A$ , di/dt  $\le -620A/\mu$ s,  $V_{DD} \le V_{(BR)DSS}$ ,  $T_J \le 175^{\circ}C$
- ④ Pulse width ≤ 300µs; duty cycle ≤ 2%

- $\ \, \ \, \ \,$  This is applied for I-PAK, L  $_{S}$  of D-PAK is measured between lead and center of die contact
- © Uses IRF6215 data and test conditions
- When mounted on 1" square PCB (FR-4 or G-10 Material ) For recommended footprint and soldering techniques refer to application note #AN-994
- ® R<sub>A</sub> is measured at TJ approximately 90°C.

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## AUIRFR6215

## **Ordering Information**

Base part	Package Type	Standard Pack		Complete Part Number
		Form	Quantity	
AUIRFR6215	Dpak	Tube	75	AUIRFR6215
AUIRFR6215		Tape and Reel	2000	AUIRFR6215TR
AUIRFR6215		Tape and Reel Left	3000	AUIRFR6215TRL
AUIRFR6215		Tape and Reel Right	3000	AUIRFR6215TRR

## International TOR Rectifier

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